AMENDMENTS TO THE CLAIMS

Please amend the claims as follows:

- (currently amended) A resist composition comprising (a) an imaging polymer, and (b) a radiation sensitive acid generator component, said radiation sensitive acid generator component comprising:
 - (i) a first radiation sensitive acid generator selected from the group consisting of dissolution-inhibiting acid generators, and
 - (ii) a second radiation sensitive acid generator selected from the group consisting of unprotected acidic group-functionalized radiation sensitive acid generators and acid labile group-protected acidic group-functionalized radiation sensitive acid generators.
- (original) The resist composition of claim 1 wherein said imaging polymer comprises a ketal-functionalized acid sensitive polymer.
- 3. (original) The resist composition of claim 1 wherein said second radiationsensitive acid generator is an acidic group-functionalized acid generator comprising an acidic moiety selected from the group consisting of phenolic moieties, carboxylic moieties and fluoroalcohol moieties.
- 4. Canceled.
- 5. (original) The composition of claim 1 wherein said resist composition contains at least about 4 wt.% of said radiation sensitive acid generator component based on the weight of said imaging polymer.
- 6. (original) The composition of claim 1 wherein said first and second acid generators are present in a mole ratio of about 5:1 to about 1:5.

- 7. (currently amended) A method of forming a patterned material structure on a substrate, said material being selected from the group consisting of organic dielectrics, semiconductors, ceramics and metals, said method comprising:
 - (A) providing a substrate with a layer of said material,
 - (B) applying a resist composition to said substrate to form a resist layer on said substrate, said resist composition comprising an imaging polymer and a radiation sensitive acid generator component, said radiation sensitive acid generator component comprising:
 - a first radiation sensitive acid generator selected from the group consisting of dissolution-inhibiting acid generators,
 and
 - (ii) a second radiation sensitive acid generator selected from the group consisting of unprotected acidic group-functionalized radiation sensitive acid generators and acid labile groupprotected acidic group-functionalized radiation sensitive acid generators,
 - (C) patternwise exposing said substrate to radiation whereby acid is generated by acid generator of the resist in exposed regions of said resist layer by said radiation,
 - (D) contacting said substrate with an aqueous alkaline developer solution, whereby said exposed regions of said resist layer are selectively dissolved by said developer solution to reveal a patterned resist structure, and

- (E) transferring resist structure pattern to said material layer, by etching into said material layer through spaces in said resist structure pattern.
- 8. (original) The method of claim 7 wherein at least one intermediate layer is provided between said material layer and said resist layer, and step (E) comprises etching through said intermediate layer.
- (original) The method of claim 7 wherein said radiation is selected from the group consisting of electron projection radiation, EUV radiation, and soft xray radiation.
- 10. (original) The method of claim 7 wherein said substrate is baked between steps (C) and (D).
- 11. (previously presented) The method of claim 7 wherein said imaging polymer comprises a ketal-functionalized acid sensitive polymer.
- 12. (original) The method of claim 7 wherein said second radiation-sensitive acid generator is an acidic group-functionalized acid generator comprising an acidic moiety selected from the group consisting of phenolic moieties, carboxylic moieties and fluoroalcohol moieties.
- 13. Canceled.
- 14. (previously presented) The method of claim 7 wherein said resist composition contains at least about 4 wt.% of said radiation sensitive acid generator component based on the weight of said imaging polymer.

- 15. (previously presented) The method of claim 7 wherein said first and second acid generators are present in a mole ratio of about 5:1 to about 1:5.
- 16. (new) The composition of claim 1 wherein said second radiation-sensitive acid generator is dimethyl (3, 5-dimethyl)-4-hydroxyphenyl sulfonium perfluorobutane sulfonate.
